Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.175 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.352 inches	
End Application:	
General purpose electronic test equipment gpete, tarawa class lha	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
T0-78	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Criticality Code Justification:	
Feat	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
15.0 breakdown voltage, dc all transistor and 5.0 collector to emitter voltage, dc all transistor and 5.0 en	nitter to base voltage, dc all
transistor	
Current Rating Per Characteristic:	
4.00 milliamperes source cutoff current all transistor	
Power Rating Per Characteristic:	
400.0 milliwatts small-signal input power, common-collector preset all transistor	
Special Features:	
Weapon system essential; transistor junction pattern arrangement: npn	
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
A110a0	